



60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE INTELLIFET MOSFET

Product Summary

V _{DS}	R _{DS(ON)}	E _{AS}	Ι _D T _A = +25°C
60V	500mΩ	120mJ	1.3A

Description

The ZXMS6004DN8Q is a dual self-protected low-side IntelliFET[®] MOSFET with logic level input. It integrates overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic level functionality. The ZXMS6004DN8Q is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

Applications

- Lamp Driver
- Motor Driver
- Relay Driver

Notes:

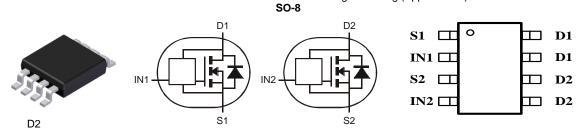
Solenoid Driver

Features and Benefits

- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto Restart
- Overvoltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Overcurrent Protection
- Input Protection (ESD)
- High Continuous Current Rating
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Characterized to AEC-Q101-006 Grade F for Short-Circuit Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (e3)
- Weight: 79.1mg (Approximate)



Ordering Information (Note 5)

Product Marking Reel Size (inches) Tape Width (mm) Quantity per Reel ZXMS6004DN80-13 6004DN8 13 12 2 500 Units					
ZXMS6004DN8Q-13 6004DN8 13 12 2 500 Units	Product		Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	ZXMS6004DN8Q-13	6004DN8	13	12	2,500 Units

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU.

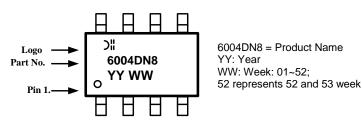
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q10x qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

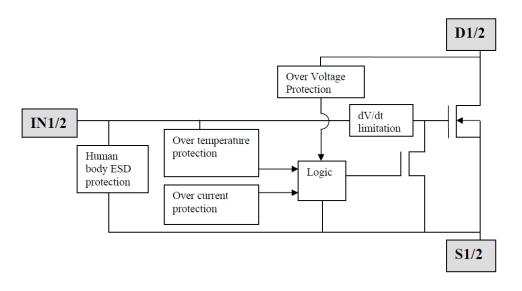
Marking Information



IntelliFET is a registered trademark of Diodes Incorporated. ZXMS6004DN8Q Document number: DS38898 Rev. 1 - 2



Functional Block Diagram



Application Information

- Two Completely Isolated Independent Channels
- Especially Suited for loads with a High In-Rush Current such as Lamps and Motors
- All Types of Resistive, Inductive and Capacitive Loads in Switching Applications
- μ C Compatible Power Switch for 12V and 24V DC Applications
- Replaces Electromechanical Relays and Discrete Circuits
- Linear Mode Capability the current-limiting protection circuitry is designed to deactivate at low V_{DS} to minimize on-state power dissipation The maximum DC operating current is therefore determined by the thermal capability of the package or board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low V_{DS}.

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Units
Continuous Drain-Source Voltage	V _{DS}	60	V
Drain-Source Voltage For Short-Circuit Protection	V _{DS(SC)}	36	V
Continuous Input Voltage	V _{IN}	-0.5 to +6	V
Continuous Input Current @ $-0.2V \le V_{IN} \le 6V$ Continuous Input Current @V _{IN} < $-0.2V$ or V _{IN} > 6V	l _{IN}	No limit │I _{IN} │≤2	mA
Pulsed Drain Current @VIN = 3.3V	I _{DM}	2	А
Pulsed Drain Current @VIN = 5V	I _{DM}	2.5	А
Continuous Source Current (Body Diode) (Note 6)	IS	1	А
Pulsed Source Current (Body Diode)	I _{SM}	5	А
Unclamped Single Pulse Inductive Energy, $T_J = +25^{\circ}C$, $I_D = 0.5A$, $V_{DD} = 24V$	E _{AS}	120	mJ
Electrostatic Discharge (Human Body Model)	V _{HBM}	4,000	V
Charged Device Model	V _{CDM}	1,000	V



Recommended Operating Conditions

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	V _{IN}	0	5.5	V
Ambient Temperature Range	T _A	-40	+125	°C
High Level Input Voltage for MOSFET to be On	VIH	3	5.5	V
Low Level Input Voltage for MOSFET to be Off	VIL	0	0.7	V
Peripheral Supply Voltage (voltage to which load is referred)	VP	0	36	V

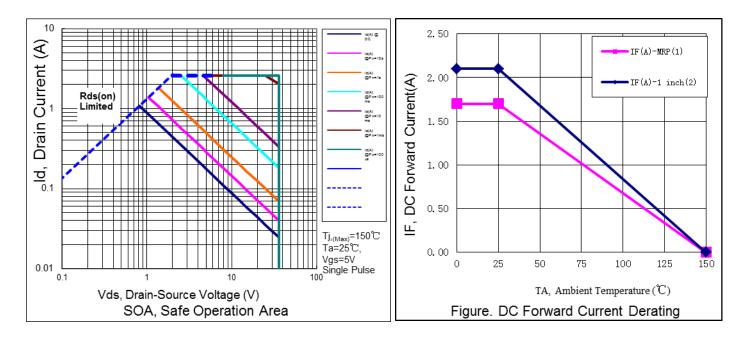
Thermal Characteristics

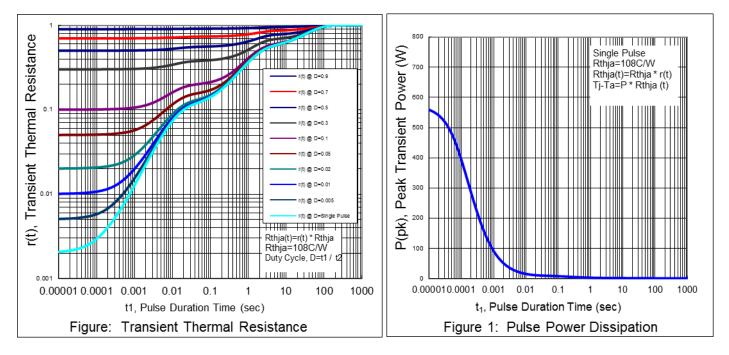
Characteristic	Symbol	Value	Units
Power Dissipation at $T_A = +25^{\circ}C$ (Note 6) Linear Derating Factor	PD	1.21 9.7	W mW/°C
Power Dissipation at $T_A = +25^{\circ}C$ (Note 7) Linear Derating Factor	PD	1.56 12.5	W mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	103	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{θJA}	81	°C/W
Thermal Resistance, Junction to Case (Note 8)	R _{θJC}	13.5	°C/W
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.
 Thermal resistance between junction and the mounting surfaces of drain and source pins. Notes:



Thermal Characteristics (Continued)







Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Static Characteristics						-	
Drain-Source Clamp Voltage	V _{DS(AZ)}	60	65	70	V	$I_D = 10 \text{mA}$	
Off-State Drain Current		_	—	1		$V_{DS} = 12V, V_{IN} = 0V$	
On-State Drain Current	I _{DSS}	_	—	2	μA	$V_{DS} = 36V, V_{IN} = 0V$	
Input Threshold Voltage	VIN(TH)	0.7	1	1.5	V	$V_{DS} = V_{GS}, I_D = 1mA$	
Input Current		_	60	100		$V_{IN} = +3V$	
Input Current	I _{IN}	_	120	200	μA	$V_{IN} = +5V$	
Input Current while Overtemperature Active	—	_	—	300	μA	V _{IN} = +5V	
Static Drain-Source On-State Resistance	D	_	400	600		$V_{IN} = +3V, I_D = 1A$	
Static Drain-Source On-State Resistance	R _{DS(ON)}	_	350	500	mΩ	$V_{IN} = +5V, I_D = 1A$	
Continuous Drain Current (Nator C)		0.9	—	—		V _{IN} = 3V; T _A = +25°C	
Continuous Drain Current (Notes 6)		1.0	—	—	A	$V_{IN} = 5V; T_A = +25^{\circ}C$	
Continuous Drain Current (Nata C)	ID	1.1	—	—		V _{IN} = 3V; T _A = +25°C	
Continuous Drain Current (Note 6)		1.2	—	—		V _{IN} = 5V; T _A = +25°C	
		0.7	1.7	—		$V_{IN} = +3V$	
Current Limit (Note 9)	I _{D(LIM)}	1	2.2	—	A	V _{IN} = +5V	
Dynamic Characteristics						-	
Turn-On Delay Time	t _{D(ON)}	_	5		μs		
Rise Time	t _R		10		μs	V _{DD} = 12V, I _D = 0.5A, V _{GS} =	
Turn-Off Delay Time	t _{D(OFF)}		45		μs	$v_{DD} = 12v, I_D = 0.5A, v_{GS} = 5v$	
Fall Time	fF	_	15	—	μs]	
Overtemperature Protection							
Thermal Overload Trip Temperature (Note 10)	T _{JT}	+150	+175	—	°C	—	
Thermal Hysteresis (Note 10)	f _F	_	+10	_	°C		

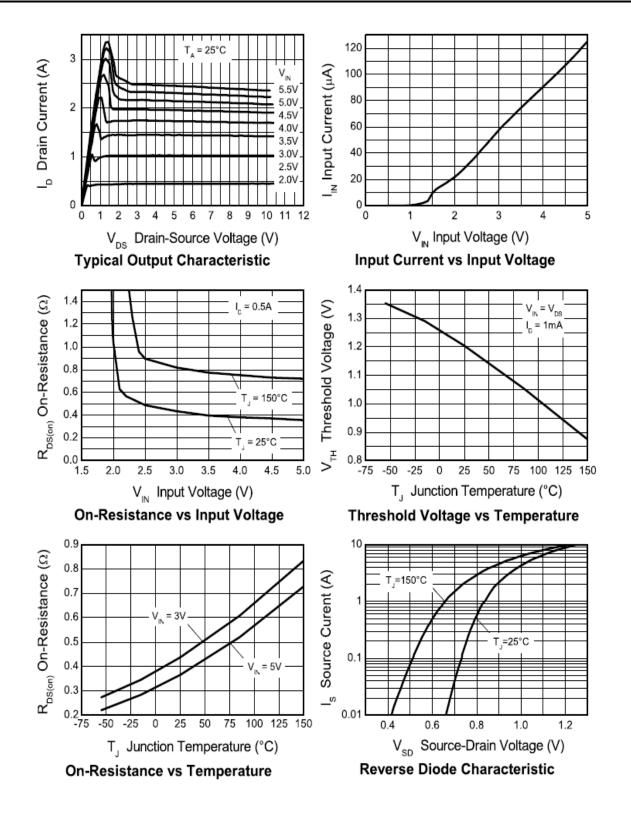
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Notes: 9. The drain current is restricted only when the device is in saturation (see graph "Typical Output Characteristic"). This allows the device to be used in the on-state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.

Saturation makes current limit unnecessary.
 Overtemperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods.

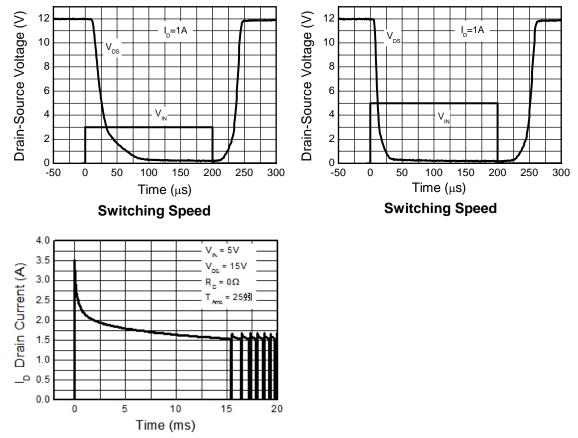


Typical Characteristics





Typical Characteristics (Continued)

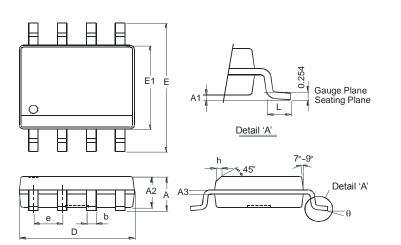


Typical Short Circuit Protection



Package Outline Dimensions

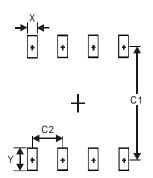
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8					
Dim	Min	Max			
Α	_	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
Е	5.90	6.10			
E1	3.85	3.95			
е	1.27 Тур				
h	_	0.35			
L	0.62	0.82			
θ	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

SO-8

SO-8



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